BEST AVAILABLE COPY

SPECIFICATION AMENDMENTS

Replace the paragraph beginning at page 1, line 9 with:

A semiconductor device has leads extending through two sides of a <u>resin</u> package thereof. In a fabrication process of semiconductor device, the leads are formed on a <u>after the</u> semiconductor device after it is covered with a resin. For example, when gull-wing type leads are formed in a prior art process, a semiconductor device, after <u>being</u> covered with a resin, is put between top and bottom dies for preliminary bending, so that lead parts extended extending from the two sides of the semiconductor device are bent with in a press working. Next, the semiconductor device is put between top and bottom dies for bending, so that distal portions of the lead parts are bent in the reverse direction by in a press working. Then, the semiconductor device having the gull-wing leads is put between top and bottom dies for adjustment, so as to have produce a final form.

Replace the paragraph beginning at page 5, line 17 with:

Fig. 4 is a diagram of an example of a device holder;

Replace the paragraph beginning at page 5, line 22 with:

Fig. 7 is a diagram for explaining fabrication of semiconductor devices of different sizes;

Replace the paragraph beginning at page 6, line 17 with:

Fig. 16 is a diagram for explaining a size of a semiconductor device;

Replace the paragraph beginning at page 6, line 21 with:

Fig. 18 is a diagram for explaining a size of a semiconductor device.